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ECL Products	

100102

Quint 2–Input OR–NOR Gate With Common Enable

FEATURES

- **Typical propagation delay: 0.75ns**
- **Typical supply current ($-I_{EE}$): 55mA**

DESCRIPTION

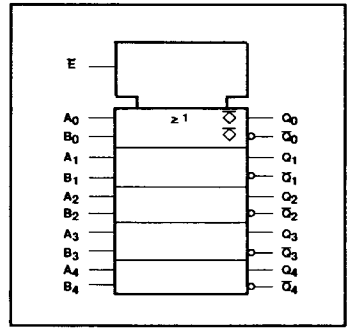
The 100102 has five 2–input OR–NOR gates with a common enable.

All unused inputs can be left open due to integrated pull–down resistors.

PIN DESCRIPTION

PINS	DESCRIPTION
$A_0 - A_4$, $B_0 - B_4$	Data Inputs
$\overline{E}$	Enable Input
$Q_0 - Q_4$	True Data Outputs (OR)
$\overline{Q}_0 - \overline{Q}_4$	Complementary Data Outputs (NOR)

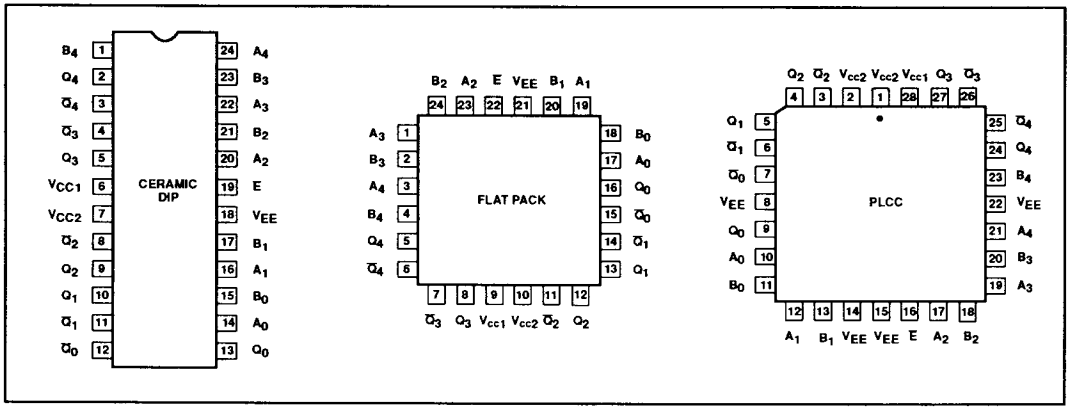
IEC/IEEE SYMBOL



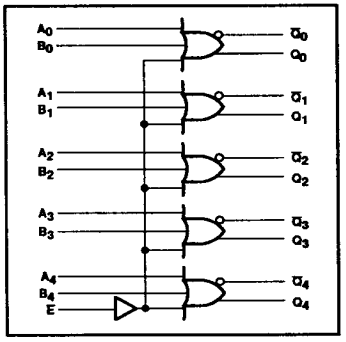
ORDERING INFORMATION

DESCRIPTION	ORDER CODE
24–Pin Ceramic DIP (400 mils wide)	100102F
24–Pin Ceramic Flat Pack	100102Y
28–Pin PLCC	100102A

PIN CONFIGURATIONS



LOGIC DIAGRAM

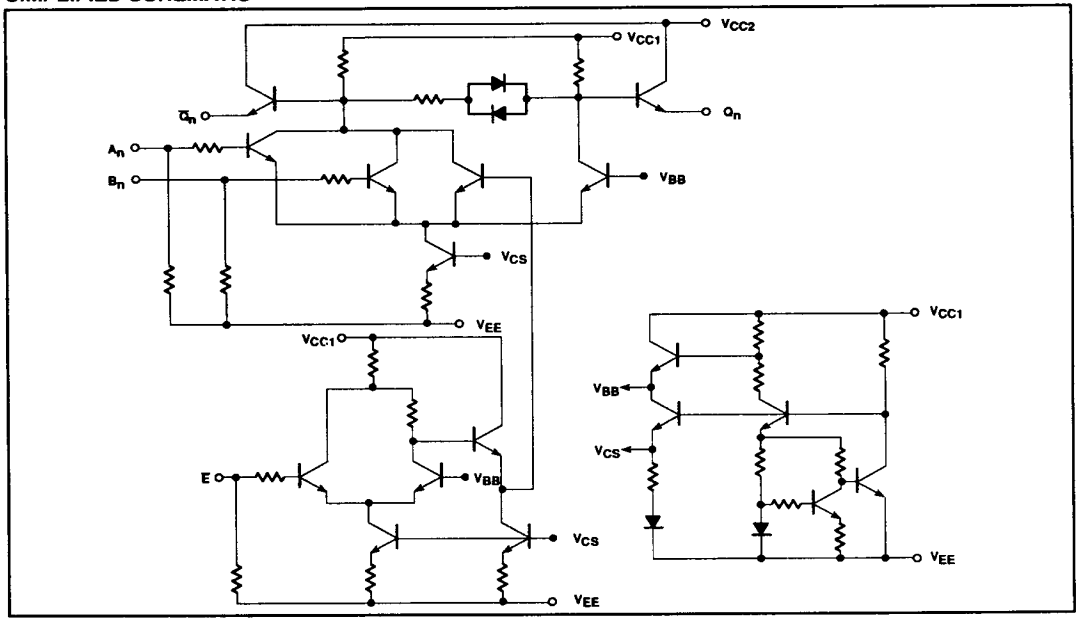


FUNCTION TABLE

INPUTS			OUTPUTS	
D_0	D_1	$\overline{E}$	Q_0	$\overline{Q}_0$
X	X	H	H	L
X	H	X	H	L
H	X	X	H	L
L	L	L	L	H

NOTES:
H = High voltage level
L = Low voltage level
X = Don't care

SIMPLIFIED SCHEMATIC



ABSOLUTE MAXIMUM RATINGS

$V_{CC1} = V_{CC2}$ = ground, T_A = 0°C to +85°C unless otherwise specified.

SYMBOL	PARAMETER	LIMITS	UNIT
V_{EE}	Supply voltage range	–7.0 to +0.5	V
V_{IN}	Input voltage (V_{IN} should never be more negative than V_{EE})	V_{EE} to +0.5	V
I_O	Output source current (continuous)	–55	mA
T_S	Storage temperature range	–65 to +150	°C
T_J	Maximum junction temperature	+150	°C

NOTE: Operation beyond the limits set forth in this table may impair the useful life of the device.

DC OPERATING CONDITIONS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN.	NOM.	MAX.	
V_{CC1}, V_{CC2}	Circuit ground		0	0	0	V
V_{EE}	Supply voltage		–4.8	–4.5	–4.2	V
V_{EE}	Supply voltage when operating with the 10K or 10KH ECL family		–5.7			V
V_{IH}	High level input voltage	V_{EE} = –4.2V	–1150		–880	mV
		V_{EE} = –4.5V	–1165			
		V_{EE} = –4.8V	–1165			
V_{IL}	Low level input voltage	V_{EE} = –4.2V	–1810		–1475	mV
		V_{EE} = –4.5V			–1475	mV
		V_{EE} = –4.8V			–1490	mV
T_A	Operating ambient temperature range		0	+25	+85	°C

NOTE:
When operating at other than the specified V_{EE} voltages (–4.2V, –4.5V, –4.8V), the DC and AC electrical characteristics will vary slightly from their specified values.

DC ELECTRICAL CHARACTERISTICS

$V_{CC1} = V_{CC2}$ = ground, V_{EE} = –4.8V to –4.2V, T_A = 0°C to +85°C unless otherwise specified[1,3,4]

SYMBOL	PARAMETER		TEST CONDITIONS[2]			LIMITS			UNIT
						MIN.	TYP.	MAX.	
V_{OH}	High level output voltage		Outputs Loaded with 50Ω to –2.0V ±0.010V	Inputs at V_{IHMAX} or V_{ILMIN}.	V_{EE} = –4.2V	–1020		–870	mV
					V_{EE} = –4.5V	–1025	–955	–880	mV
					V_{EE} = –4.8V	–1035		–880	mV
V_{OHT}	High level output threshold voltage			Apply V_{IHMIN} or V_{ILMAX} to one input at a time, other inputs at V_{IHMAX} or V_{ILMIN}.	V_{EE} = –4.2V	–1030			mV
					V_{EE} = –4.5V	–1035			mV
					V_{EE} = –4.8V	–1045			mV
V_{OLT}	Low level output threshold voltage			Apply V_{IHMIN} or V_{ILMAX} to one input at a time, other inputs at V_{IHMAX} or V_{ILMIN}.	V_{EE} = –4.2V			–1595	mV
					V_{EE} = –4.5V			–1610	mV
					V_{EE} = –4.8V			–1610	mV
V_{OL}	Low level output voltage			Inputs at V_{IHMAX} or V_{ILMIN}.	V_{EE} = –4.2V	–1810		–1605	mV
					V_{EE} = –4.5V	–1810	–1705	–1620	mV
					V_{EE} = –4.8V	–1830		–1620	mV
I_{IH}	High level input current	D_n inputs	One input under test at V_{IHMAX}. Other inputs at V_{ILMIN}.					350	µA
		$\overline{E}$ input						300	µA
I_{IL}	Low level input current		One input under test at V_{ILMIN}. Other inputs at V_{IHMAX}.			0.5			µA
$-I_{EE}$	V_{EE} supply current		All inputs at V_{IHMAX}.			38	55	80	mA

NOTES:
1. The specified limits represent the worst case values for the parameter. Since these worst case values normally occur at the supply voltage and temperature extremes, additional noise immunity can be achieved by decreasing the allowable operating condition ranges.
2. Conditions for testing shown in the tables are not necessarily worst case. For worst case testing guidelines, refer to DC Testing, Chapter 1, Section 3.
3. The specified limits shown in the DC electrical characteristics table can be met only after thermal equilibrium has been established. Thermal equilibrium is established by applying power for at least 2 minutes, while maintaining transverse airflow of 2.5 meters/sec (500 linear feet/min) over the device, mounted either in a test socket or on a printed circuit board. Test voltage values are given in the DC operating conditions table.
4. The device can function down to V_{EE} = –5.7V, allowing operation with either the 10K or the 10KH family. Correction factors can be used to calculate new DC limits for the extended V_{EE} range. For more information, see Chapters 5 and 10, Section 4.

AC ELECTRICAL CHARACTERISTICS

Ceramic DIP $V_{CC1} = V_{CC2}$ = ground, V_{EE} = –4.8V to –4.2V

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			T_A = 0°C		T_A = +25°C		T_A = +85°C		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay D_n to Q_n or $\overline{Q}_n$	Waveform 1	0.45 0.45	1.35 1.35	0.45 0.45	1.15 1.15	0.45 0.45	1.40 1.40	ns ns
t_{PLH} t_{PHL}	Propagation delay $\overline{E}$ to Q_n or $\overline{Q}_n$		0.90 0.90	2.15 2.15	0.95 0.95	2.15 2.15	0.95 0.95	2.20 2.20	ns ns
t_{TLH} t_{THL}	Transition time Q_n or $\overline{Q}_n$		0.45 0.45	1.20 1.20	0.45 0.45	1.10 1.10	0.45 0.45	1.10 1.10	ns ns

NOTE:
For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC ELECTRICAL CHARACTERISTICS

Ceramic DIP $V_{CC1} = V_{CC2}$ = ground, V_{EE} = –5.2V ± 5%

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			T_A = 0°C		T_A = +25°C		T_A = +85°C		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay D_n to Q_n or $\overline{Q}_n$	Waveform 1	0.45 0.45	1.35 1.35	0.45 0.45	1.15 1.15	0.45 0.45	1.40 1.40	ns ns
t_{PLH} t_{PHL}	Propagation delay E to Q_n or $\overline{Q}_n$		0.90 0.90	2.15 2.15	0.95 0.95	2.15 2.15	0.95 0.95	2.20 2.20	ns ns
t_{TLH} t_{THL}	Transition time Q_n or $\overline{Q}_n$		0.45 0.45	1.20 1.20	0.45 0.45	1.10 1.10	0.45 0.45	1.10 1.10	ns ns

NOTE:
For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC ELECTRICAL CHARACTERISTICS

Flat Pack and PLCC $V_{CC1} = V_{CC2}$ = ground, V_{EE} = –4.8V to –4.2V

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			T_A = 0°C		T_A = +25°C		T_A = +85°C		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay D_n to Q_n or $\overline{Q}_n$	Waveform 1	0.45 0.45	1.15 1.15	0.45 0.45	0.95 0.95	0.45 0.45	1.20 1.20	ns ns
t_{PLH} t_{PHL}	Propagation delay E to Q_n or $\overline{Q}_n$		0.90 0.90	1.95 1.95	0.95 0.95	1.95 1.95	0.95 0.95	2.00 2.00	ns ns
t_{TLH} t_{THL}	Transition time Q_n or $\overline{Q}_n$		0.45 0.45	1.20 1.20	0.45 0.45	1.10 1.10	0.45 0.45	1.10 1.10	ns ns

NOTE:
For AC test setup information, see AC Testing, Chapter 2, Section 3.

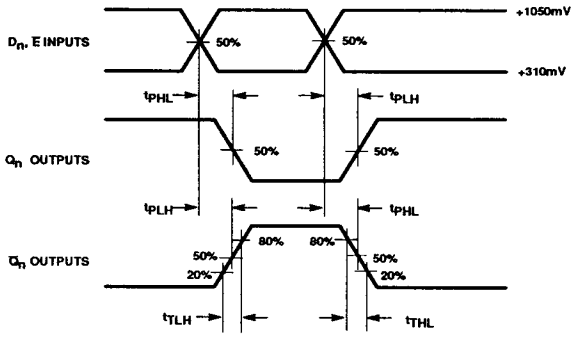
AC ELECTRICAL CHARACTERISTICS

Flat Pack and PLCC $V_{CC1} = V_{CC2} = \text{ground}$, $V_{EE} = -5.2V \pm 5\%$

SYMBOL	PARAMETER	TEST CONDITION	LIMITS						UNIT
			$T_A = 0°C$		$T_A = +25°C$		$T_A = +85°C$		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{PLH} t_{PHL}	Propagation delay D_n to Q_n or $\overline{Q}_n$	Waveform 1	0.45 0.45	1.15 1.15	0.45 0.45	0.95 0.95	0.45 0.45	1.20 1.20	ns ns
t_{PLH} t_{PHL}	Propagation delay $\overline{E}$ to Q_n or $\overline{Q}_n$		0.90 0.90	1.95 1.95	0.95 0.95	1.95 1.95	0.95 0.95	2.00 2.00	ns ns
t_{TLH} t_{THL}	Transition time Q_n or $\overline{Q}_n$		0.45 0.45	1.20 1.20	0.45 0.45	1.10 1.10	0.45 0.45	1.10 1.10	ns ns

NOTE:
For AC test setup information, see AC Testing, Chapter 2, Section 3.

AC WAVEFORMS



Waveform 1. Propagation Delay and Transition Times

NOTE:
All power and signal voltages shifted up 2.0V for AC bench test purposes.